FORM PTO-1449 (*modified*)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT(S)
(Use several sheets if necessary)

ATTY DOCKET NO.	APPLICATION NO.
35.C5745 CIP/C2/D2/REI	09/587,249

APPLICANT	
SEISHIRO YOSHIOKA ET AL.	

FILING DATE	GROUP 1722
June 2, 2000	1722

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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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